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## Overview of Silicon Carbide Detectors: from material properties to radiation hardness

Wednesday, 26 February 2025 09:30 (30 minutes)

In this talk an overview of the advantage of silicon carbide detectors will be presented in terms of leakage current, signal resolution and radiation hardness. To obtain high performance in the detectors for different applications, a new growth process of the epitaxial layers has been developed and the characteristics of the epitaxial layers have been obtained by electrical measurements. Furthermore, these detectors with different structures have been used in different applications (neutrons, high energy particles, UV, X-Ray, …) and the main results of these detectors will be reported in this overview. Finally, a specific study on the radiation hardness of these detectors for high energy particles and of the effect of high temperature in the detection of neutrons will be presented.

**Presenter:** Dr LA VIA, Francesco (CNR-IMM. Catania, Italy) **Session Classification:** Day 3 - Session 1